

Supporting Information

The Critical Role of Surface Dipoles in CsPbI₃ Perovskite Solar Cells

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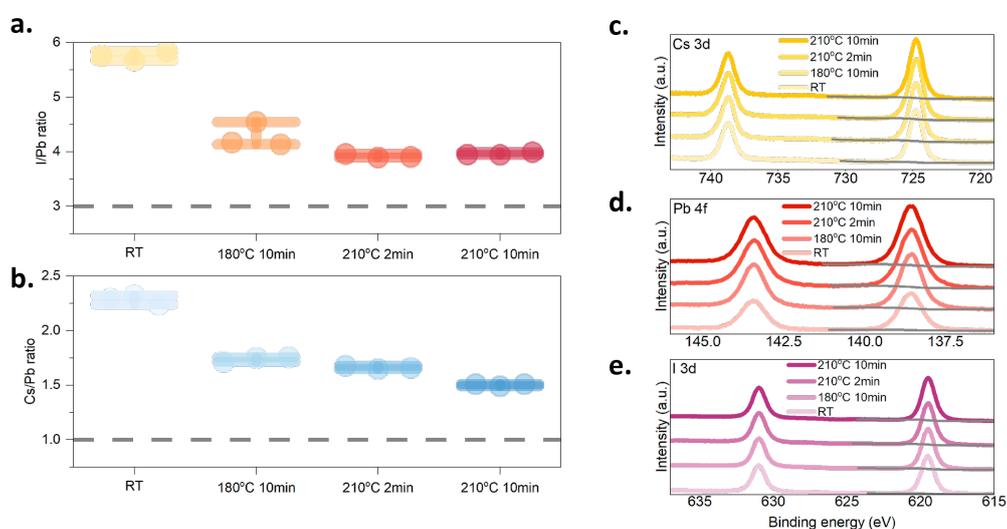


Figure S1 a. I/Pb, and b. Cs/Pb element ratio distribution of CsPbI₃ films with different annealing conditions. The values were obtained from XPS measurements, with three different areas tested under each condition to ensure repeatability. Representative XPS spectra are shown in c. (Cs 3d), d. (Pb 4f), and e. (I 3d).

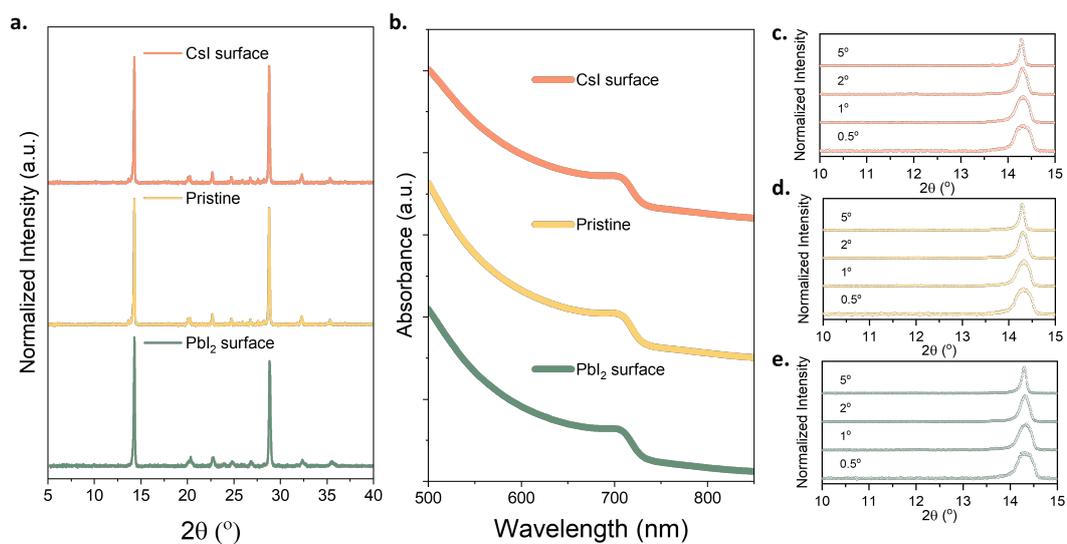


Figure S2 a. XRD patterns, b. UV-Vis absorption spectra, and patterns of CsPbI₃ films with varied surface conditions.

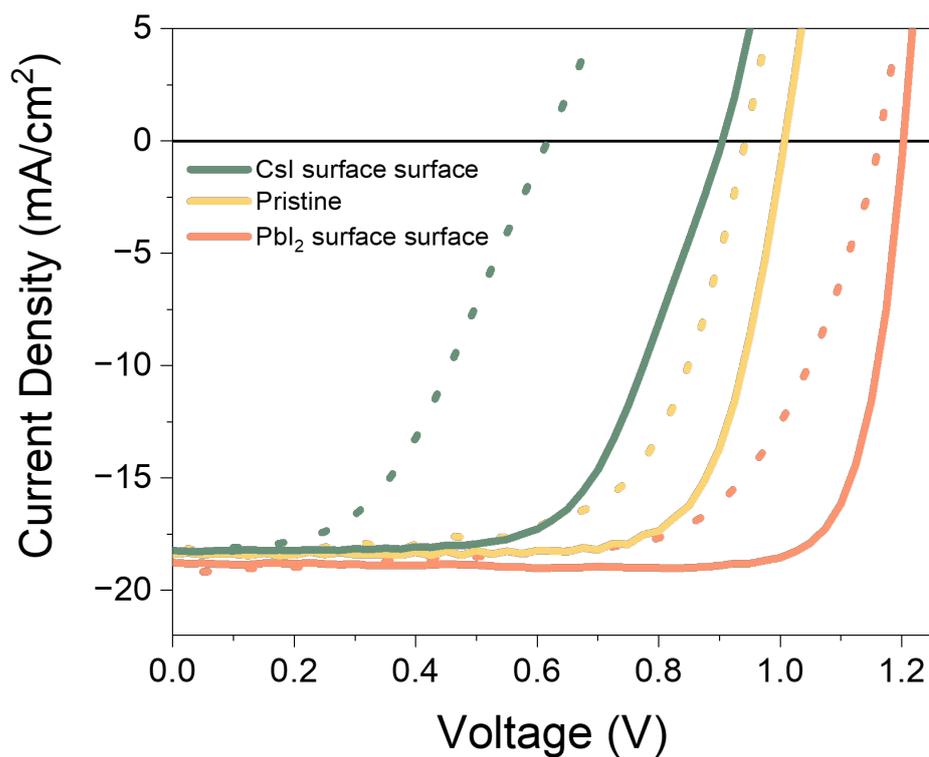


Figure S3 J-V characteristics of Figure 2f measured with forward and reverse scans. The dashed line represents the forward scan, and the solid line represents the reverse scan.

Table S1 PV parameters of solar cells with treated-CsPbI₃ active layers in Figure 4.

	V _{oc} (V) Forward	J _{sc} (mA/cm ²) Forward	FF (%) Forward	PCE (%) Forward	V _{oc} (V) Backward	J _{sc} (mA/cm ²) Backward	FF (%) Backward	PCE (%) Backward	Maximum PCE (%)	Hysteresis Index
PbI ₂	1.16±0.02	-19.81±0.60	59.58±8.37	13.63±1.47	1.19±0.01	-18.66±0.65	82.98±0.31	18.44±0.61	19.17	0.26±0.15
PbBr ₂	1.16±0.01	-19.52±0.88	70.22±4.49	15.90±0.85	1.18±0.01	-19.31±0.65	82.00±0.16	18.76±0.66	19.73	0.15±0.11
PbCl ₂	1.15±0.04	-19.02±1.05	71.37±4.88	15.63±0.82	1.19±0.01	-18.95±0.97	81.56±0.09	18.40±0.98	19.60	0.15±0.12
DAB	1.13±0.02	-19.31±0.42	72.09±7.07	15.64±1.25	1.15±0.00	-18.95±0.33	80.73±1.51	17.62±0.42	18.20	0.11±0.13
Methnol	1.10±0.04	-18.95±0.25	70.34±5.74	14.72±1.28	1.14±0.00	-18.68±0.51	79.66±1.39	17.02±0.52	17.57	0.14±0.19
Pristine	0.95±0.04	-18.88±0.63	64.53±2.23	11.55±0.52	1.00±0.01	-18.84±0.52	72.26±1.64	13.68±0.39	14.31	0.15±0.14
CsF	0.87±0.10	-17.66±0.75	58.36±3.17	9.00±1.48	0.93±0.01	-17.66±0.75	64.67±2.46	10.60±0.83	11.60	0.15±0.34
CsI	0.80±0.10	-18.63±0.82	55.20±5.22	8.37±1.90	0.90±0.00	-18.63±0.82	63.35±1.10	10.65±0.47	11.53	0.22±0.47
CsBr	0.79±0.05	-18.31±1.00	53.81±5.44	7.85±1.54	0.84±0.01	-18.31±1.00	59.05±3.47	9.09±0.76	10.09	0.14±0.28
RbI	0.68±0.10	-18.24±0.44	52.74±10.25	6.68±2.11	0.78±0.01	-18.24±0.44	63.05±3.50	8.98±0.68	10.29	0.26±0.51

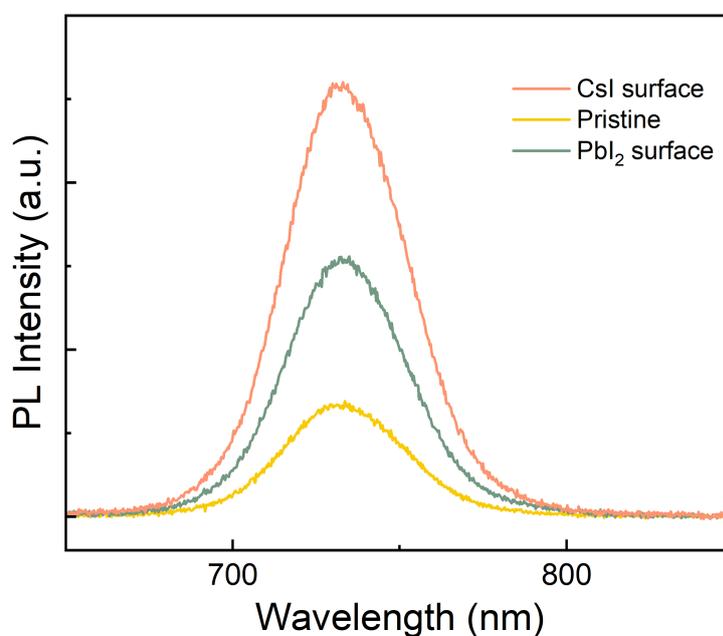


Figure S4 1-sun steady-state photoluminescence (PL) spectra of complete CsPbI₃ perovskite solar cells with architecture of ITO/MeO-2PACz/CsPbI₃/PCBM/BCP/Ag.

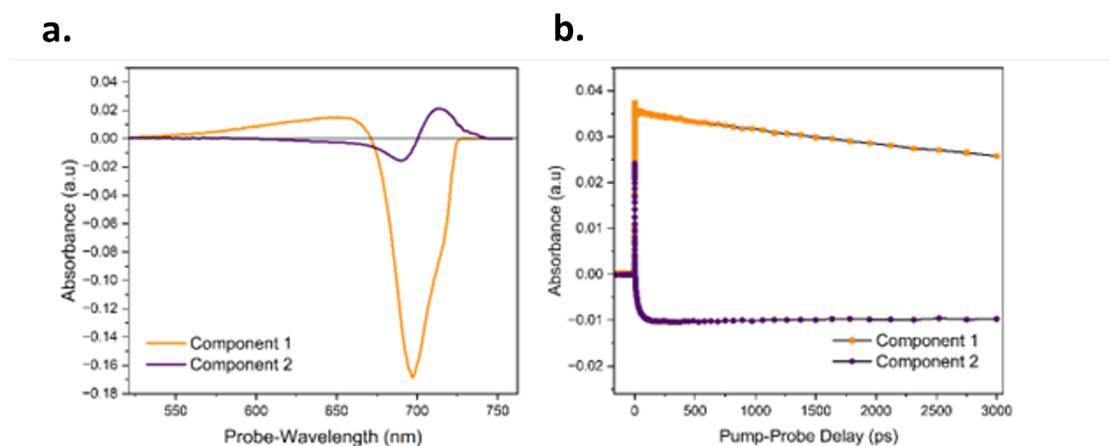


Figure S5 a. component-spectra and b. associated dynamics retrieved from the Singular Value Decomposition of CsPbI₃/PbI₂/PCBM TAS-data given in Figure 3. Component 1 incorporates the negative GSB-signal at 700nm alongside a broad photoinduced absorption signal around 665 nm. The spectral shape and kinetics of component 2 are consistent with energetic redistribution processes arising from hot-carrier and band-filling effects.

Table S2 Tabulated lifetimes of the kinetics given in Figure 3e.

System	Average Lifetime (ns)		Change in Lifetime (ns)
	Bare System (No PCBM)	Interfaced with PCBM	
CsPbI₃	8.03 ± 0.1	5.41 ± 0.21	2.62 ± 0.31
PbI₂ surface	11.08 ± 0.18	6.96 ± 0.24	4.12 ± 0.44
CsI surface	9.62 ± 0.13	8.56 ± 0.19	1.06 ± 0.32

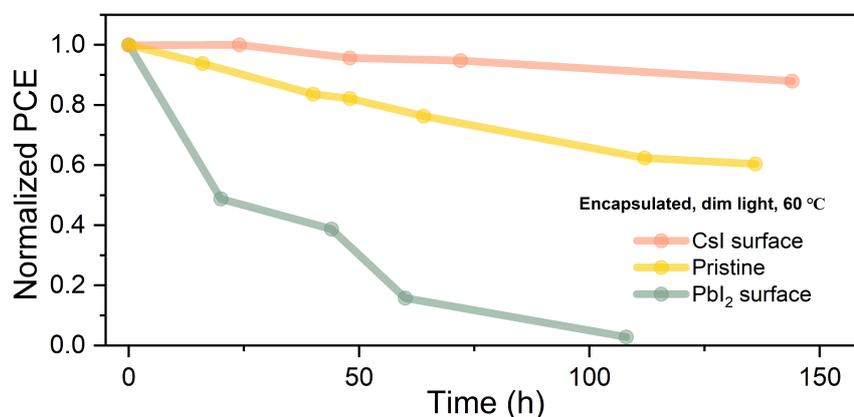


Figure S6. Performance evolution of treated CsPbI₃ solar cells with encapsulation. Up to 150 h stability was tested under dim light, 60 °C

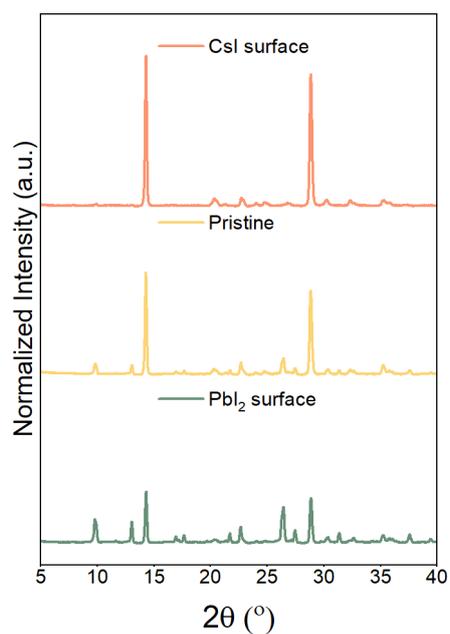


Figure S7 XRD patterns of treated CsPbI₃ films after degradation. The condition is maintained under continuous illumination for up to 250 h at 20% relative humidity (RH) and 25 °C.

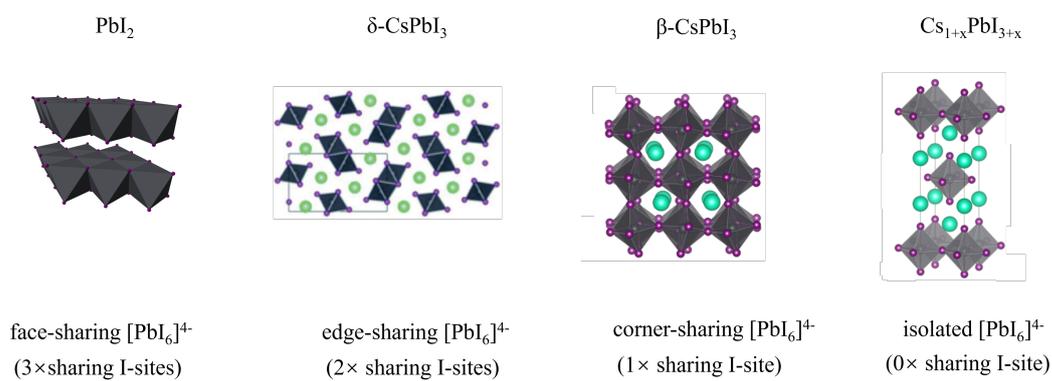


Figure S8 Schematic diagram of the crystallographic structure of PbI₂, δ-CsPbI₃, β-CsPbI₃, and Cs_{1+x}PbI_{3+x}.